

A Systematic Study of Structures, Stability, and Electronic Properties of alloy clusters AlBe_n ($n = 1-12$): Comparison with Pure Beryllium Clusters

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Abstract

The geometric structures, energetic and electronic properties of global minima of the AlBe_n ($n = 1-12$) clusters have been systemically studied by using the hybrid density functional theory [B3LYP] and coupled cluster [CCSD(T)] methods. It is found that the impurity Al atom is externally bound to the host Be framework and its maximum coordination number is six. Besides, the geometries of AlBe_n bear close resemblance to either local or global minimum structures of Be_{n+1} . The AlBe_3 and AlBe_8 clusters exhibit high relative stability among the AlBe_n clusters, which is reflected by the evolutions of average atomic binding energy, dissociation energy, second difference in energy, adsorption energy of Al, and HOMO-LUMO gap with cluster size. In comparison to the pure Be_{n+1} clusters, AlBe_n exhibit larger binding energy values, whereas they are more polarizable.

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Introduction

As a bridge between atoms and macroscopic state, cluster science continues to be a subject of increasing research interest. In the realm of cluster investigations, metal clusters^[1-7] have attracted extensive attention in the last several decades because they exhibit many intriguing properties that are neither atomic-like nor extended solidlike,^[8,9] while being closely connected to size, geometry, and composition. These size-dependent properties offer exciting possibilities for developing finely tuned cluster-assembled materials, which have promising applications in the fields of material science, optics, nanotechnology, catalysis, etc.^[10-14] Besides, it has long been recognized that the properties of metal clusters, instead of evolving linearly with size, usually vary discontinuously with the number of component atoms.^[11] In this respect, a simple yet helpful free-electron model, namely spherical jellium model (SJM),^[15] has been proposed to account for the evolution of properties (even structures) of numerous pure and doped metal clusters.^[16,17]

The fact that beryllium dimer is weakly bound^[18-22] whereas bulk beryllium is a hard metal with rather high melting point and enthalpy of atomization^[23] makes beryllium cluster an ideal prototype for exploring the evolution from discrete molecules to metallic state, as indicated in an overview on the studies of beryllium

clusters.^[24] In contrast to experimental studies which are limited by the toxicity of beryllium, quantum chemistry provides powerful computational methods that help to investigate beryllium clusters in detail. By using density functional theory with Becke–Lee–Yang–Parr gradient correction, Wang et al.^[25] studied the structural and electronic properties of beryllium clusters containing up to 21 atoms, and they found that the Be₄, Be₁₀ and Be₁₇ clusters show particularly high stability. With the help of a modified genetic algorithm, Khanna and coworkers^[26] have revealed the dependence of relative stability and electronic properties of the Be_n ($n = 2 - 41$) clusters on their equilibrium geometries.

Recently, doped metal clusters have attracted much attention from both theoretical and experimental researchers. It has been found that the characteristics of pure metal clusters, such as relative stability, structural evolution, bonding character, electronic and magnetic properties, etc., are usually altered when a heteroatom is introduced. Consequently, doped clusters may show new physicochemical properties not found in pure clusters. In this study, we focus on doped beryllium clusters and choose Al atom as the dopant atom. On the one hand, impurity-atom doping may provide additional flexibility to modulate the physical and chemical properties of beryllium clusters. On the other hand, the systematical study of beryllium-aluminum binary clusters is a meaningful project in view of the important applications of Be-Al alloys in disk drive armatures, automotive braking systems, and aerospace and satellite system components.^[27-30]

In the present work, we have performed a comprehensive study of the bimetallic AlBe_n ($n = 1-12$) clusters. Besides exploring the ground state structures, we also aim to reveal the evolution of structures, stability, and various electronic structure related properties of AlBe_n along with cluster size. Furthermore, we make a comparison between AlBe_n and pure Be_{n+1} clusters from all aspects to analyze the Al-substitution effect. We hope that results from this study will not only offer a fundamental understanding of structure-property relationship of subnano-scale beryllium-aluminum clusters, but provide useful references for studies of other binary metal clusters.

2. Methods

The lowest-energy structures of the AlBe_n ($n = 1-12$) clusters were identified by using two methods, for both of which the spin multiplicity of 2 and 4 were taken into account. In the first one, a large number of AlBe_n geometries were manually built on the basis of those of pure beryllium clusters.^[16] We have obtained various structures where the impurity Al atom is either attached to each possible site of the Be_n cluster or used to substitute one Be atom of the host Be_{n+1} cluster. In the second one, a stochastic search procedure^[2] was used to make sure that all the global minimum structures have been found. This procedure can generate structures randomly, and hence facilitates a thorough exploration of unknown isomers. With this method, a great number of starting geometries were obtained at the B3LYP/LANL2DZ level. Afterwards, much more hunts were performed in the region of these structures to do an intensive search until no new minima appeared. Then, all the possible initial structures obtained from these two methods were optimized with subsequent frequency analysis at the B3LYP/aug-cc-pVDZ level to identify the lowest-energy ones.

To examine the energetic and electronic properties of the AlBe_n clusters, single-point calculations were performed by using both B3LYP and CCSD(T) methods with the aug-cc-pVDZ basis set. Natural bond orbital (NBO) analysis^[33] was carried out at the B3LYP/aug-cc-pVDZ level. At the same computational level, the spherically averaged polarizability (α) of AlBe_n were calculated, which is defined as the mean value of diagonal terms of the polarizability matrix, namely,

All calculations were carried out by using the GAUSSIAN 09^[34] program package. Dimensional diagrams of the molecular structures and orbitals were generated with the GaussView program.^[35]

RESULTS AND DISCUSSION

3.1 Geometrical structures

First, we focus on the geometrical evolution of the AlBe_n ($n = 1-12$) clusters. To explore the Al substitution effect on beryllium clusters, the structures of Be_{n+1} were also obtained on the basis of previous reports^[25,26,36] and reoptimized at the B3LYP/aug-cc-pVDZ level. The lowest-energy structures of AlBe_n

along with the corresponding global and local minima of the Be_{n+1} ($n = 1-12$) clusters are presented in Figure 1, where their spin multiplicity are also shown. It has been found that all the global minima of AlBe_n are in doublet states except for AlBe_7 corresponding to a quartet state. The symmetry, number of Al-Be bonds, the lowest vibrational frequencies, the shortest Al-Be bond lengths, as well as the HOMO-LUMO gaps of the most stable AlBe_n ($n = 1-12$) clusters are listed in Table 1.

The ground state structure of AlBe has a bond length of 2.439 Å and vibrational frequency of 374 cm^{-1} , according well with experimental results ($R = 2.395$ Å, $v = 382$ cm^{-1})^[37] and previously reported theoretical results ($R = 2.430$ Å, $v = 385$ cm^{-1} ;³⁷ $R = 2.423$ Å, $v = 375$ cm^{-1} ;^[38] $R = 2.434$ Å, $v = 379.6$ cm^{-1} ;^[39]). Thus, the B3LYP/aug-cc-pVDZ treatment is considered reliable for predicting the structures of the AlBe_n clusters. The global minimum of AlBe_2 exhibits an isosceles triangular structure with C_{2v} symmetry, in which the Al-Be and Be-Be bond lengths are 2.302 Å and 2.153 Å, respectively. Note that the Be-Be bond length of AlBe_2 is shorter by 0.351 Å than that of Be_2 , indicating that the Be-Be bond strength of Be_2 has been enhanced by the attachment of Al atom. Likewise, the Al-Be bond of AlBe_2 is also shorter than that of AlBe .

The transition from two-dimensional (2D) to three-dimensional (3D) structures occurs at $n = 3$ in this series. From Figure 1, a tetrahedral configuration (C_{3v}) is obtained for AlBe_3 , where the Al atom caps a equilateral triangular Be_3 unit. In this structure, the Al-Be and Be-Be bond lengths are 2.324 Å and 2.048 Å, respectively. The latter is just equal to that of the lowest-energy structure of Be_4 . In the case of AlBe_4 , the most stable structure is a C_s -symmetric trigonal bipyramid with the Al atom at the top site. This structure contains two short Al-Be bonds of 2.339 Å and a long Al-Be bond of 2.721 Å.

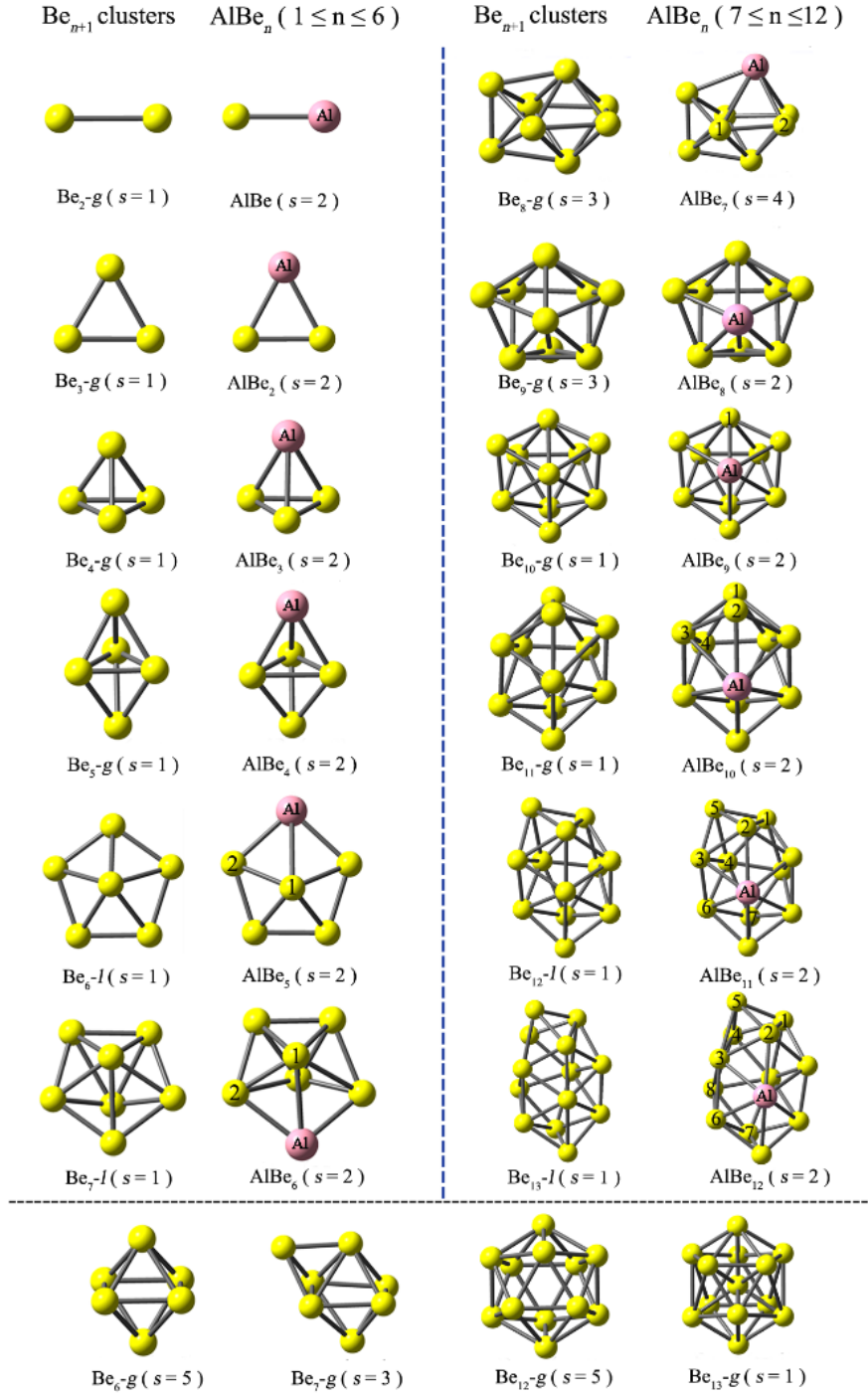


Figure 1. Ground-state geometries of the host Be_{n+1} clusters ($1 \leq n \leq 12$) on the left side. The lowest-energy structures of the AlBe_n clusters ($1 \leq n \leq 12$) on the right. In the bottom, the global minimum structures of Be_{n+1} ($n = 5, 6, 11$, and 12) are shown. $\text{Be}_n\text{-g}$ represents a global minimum and the $\text{Be}_n\text{-l}$ represents a local minimum and the multiplicity of each structure is displayed in parentheses. Be atoms are

shown as yellow spheres while Al atoms in pink color.

It can be noticed that, from AlBe to AlBe_4 , the larger structure can be obtained by attaching a Be atom to the smaller one. As for AlBe_5 , the lowest-energy structure prefers a C_s -symmetric cap-like configuration, which looks similar to a metastable structure of Be_6 (Be_6-l in Figure 1). The Al-Be1 and Al-Be2 bond lengths of AlBe_5 are 2.610 Å and 2.274 Å, respectively, and the Be-Be bond lengths vary from 1.992 Å to 2.167 Å. The lowest-lying state of AlBe_6 has a pentagonal bipyramidal geometry of C_2 symmetry. It can be obtained by attaching a Be atom to AlBe_5 from the opposite side of the Be1 atom, which accordingly shortens the Al-Be1 bond by 0.127 Å. Just like the case of AlBe_5 , the ground state of AlBe_6 has a similar configuration to that of a local, but not global, minimum of Be_7 . The most stable structure of AlBe_7 presents a bicapped octahedral structure, which can be obtained by either duplicating the Be2 atom of AlBe_6 or substituting an Al for the top Be atom in the global minimum of Be_8 (Be_8-g). Note that a similar structure with a spin multiplicity of 2 was also obtained for AlBe_7 , whereas it is 4.47 kcal/mol less stable than the quartet state.

As can be seen from Figure 1, each structure of the AlBe_n ($n = 8-12$) series could be generated by attaching a Be atom to that of AlBe_{n-1} . The lowest-energy structure of AlBe_8 can also be regarded as a result of substituting an Al atom for a Be atom in Be_9-g . A 16-faced deltahedron was identified to be the most stable structure of AlBe_9 . Obviously, this structure can be obtained by an additional Be atom face-capping the bottom of AlBe_8 . Meanwhile, it quite resembles the global minimum structure of Be_{10} . The ground-state structure of AlBe_{10} bears strong resemblance to that of Be_{11} . It can be considered derived from AlBe_9 by twinning the top Be1 atom of the latter. The global minimum of AlBe_{11} presents a capsule geometry derived from a local minimum structure (Be_{12-l}) of Be_{12} instead of the icosahedral Be_{12-g} . On the other hand, face-capping the AlBe_{10} polyhedron can also generate the structure of AlBe_{11} . Meanwhile, the introduction of the Be5 atom leads to lengthened Be1-Be3 distance (from 2.095 Å to 3.102 Å), so the Be1-Be3 bond is broken in AlBe_{11} . The most stable structure of AlBe_{12} can be regarded as the result of attaching a Be (Be_8) atom to AlBe_{11} , accompanied by broken Be4-Be6 and Be4-Be7 bonds. In this group of structures, the Al-Be bond lengths range from 2.285 Å to 2.505 Å and the Be-Be bond lengths are 2.044–2.220 Å.

Table 1. Symmetry Point Groups, the Number of Be-Al Bonds (N), the Shortest Be-Al Bond Lengths ($R_{\text{Be-Al}}$, in Å), the Lowest Vibrational Frequencies (ν , in cm^{-1}), and the HOMO-LUMO Gaps (in eV) of the Lowest-energy AlBe_n ($n = 1-12$) Clusters.

Isomers	Symmetry	N	$R_{\text{Be-Al}}$	ν	gap
AlBe	$C_{[2]v}$	1	2.439	374	1.398
AlBe_2	C_{2v}	2	2.302	415	1.714
AlBe_3	C_{3v}	3	2.324	376	2.194
AlBe_4	C_s	3	2.339	87	1.661
AlBe_5	C_s	3	2.274	113	2.062
AlBe_6	C_2	4	2.289	67	1.482
AlBe_7	C_s	5	2.323	127	2.514
AlBe_8	C_s	5	2.285	212	2.817
AlBe_9	C_{3v}	6	2.362	215	2.324
AlBe_{10}	C_2	6	2.344	215	2.036
AlBe_{11}	C_1	6	2.309	203	1.758
AlBe_{12}	C_1	6	2.306	187	1.754

As discussed above, there is a counterpart for each lowest-energy structure of AlBe_n in the minimum structures of their corresponding Be_{n+1} cluster. Besides, as can be seen in Table 1, the number of Al-Be bonds in AlBe_n increases with the increasing cluster size and reaches a maximum value of six. It implies that the impurity Al atom is able to bond with six Be atoms at most. These rules may help to identify the low-lying structures of larger Al-doped Be_n clusters.

The comparison between AlBe_n and other Al-doped clusters shows how the relative size of impurity atom

affects the structural evolution of the whole system. For example, the impurity Al atom always occupies an external position of the host clusters in AlBe_n and AlB_n [40] until $n = 12$, while it gets trapped in the host cage from $n = 6$ onwards in AlLi_n [41] and AlNa_n , [42,43] and from $n = 9$ onwards in the AlTi_n , [44] AlSc_n , [45] AlPb_n , [46] and AlY_n [47] clusters. These structural distinctions can be related to the size difference of the dopant atom versus the host atom. To be specific, the impurity Al atom (1.25 Å) [48] has larger atomic radius than those of B (0.85 Å) and Be (1.05 Å) atoms, which hinders it from entering the B_n or Be_n cages. In contrast, a framework constituted by larger host atoms such as Li (1.45 Å), Na (1.80 Å), Ti (1.40 Å), Sc (1.60 Å), Pb (1.80) and Y (1.80 Å) can accommodate the dopant Al atom.

3.2 Stability and Electronic Properties

3.2.1 Stability

The relative stability of different sized AlBe_n clusters can be discussed on the basis of binding energy per atom (E_b), dissociation energy (ΔE), and the second difference in energy ($\Delta^2 E$), where

These energetic properties, calculated at the CCSD(T)//B3LYP and B3LYP levels, are listed in Table S1 in supporting information. From the table, the B3LYP method overestimates binding energies and dissociation energies by 0.103–0.254 eV and 0.147–0.387 eV, respectively, when compared with the CCSD(T) results. Nevertheless, the E_b and ΔE values obtained by both methods show consistent trends. Besides, the B3LYP results of $\Delta^2 E$ accord well with those at the CCSD(T) level, and the differences are 0.033 eV–0.240 eV.

To explore the Al-substitution effect on the stability of bare beryllium clusters, the above-mentioned quantities of Be_{n+1} were also calculated according to the following equations,

For comparison, the size dependence of these energetic properties for the lowest-energy AlBe_n and Be_{n+1} ($n = 1-12$) clusters are plotted in Figure 2. It is known that small bumps and dips in the E_b curve are indicative of relative stability and reactivity for corresponding clusters, respectively. From Figure 2a, the E_b values of AlBe_n and Be_{n+1} increase sharply first, then, both curves reach a plateau from $n = 3$ to $n = 5$ and then rise again as cluster size grows. It is noted that the E_b value of an AlBe_n cluster is larger by 0.033–0.324 eV than that of its corresponding Be_{n+1} cluster, suggesting that the substitution of an Al atom for a Be atom in Be_{n+1} can enhance the intracuster binding force.

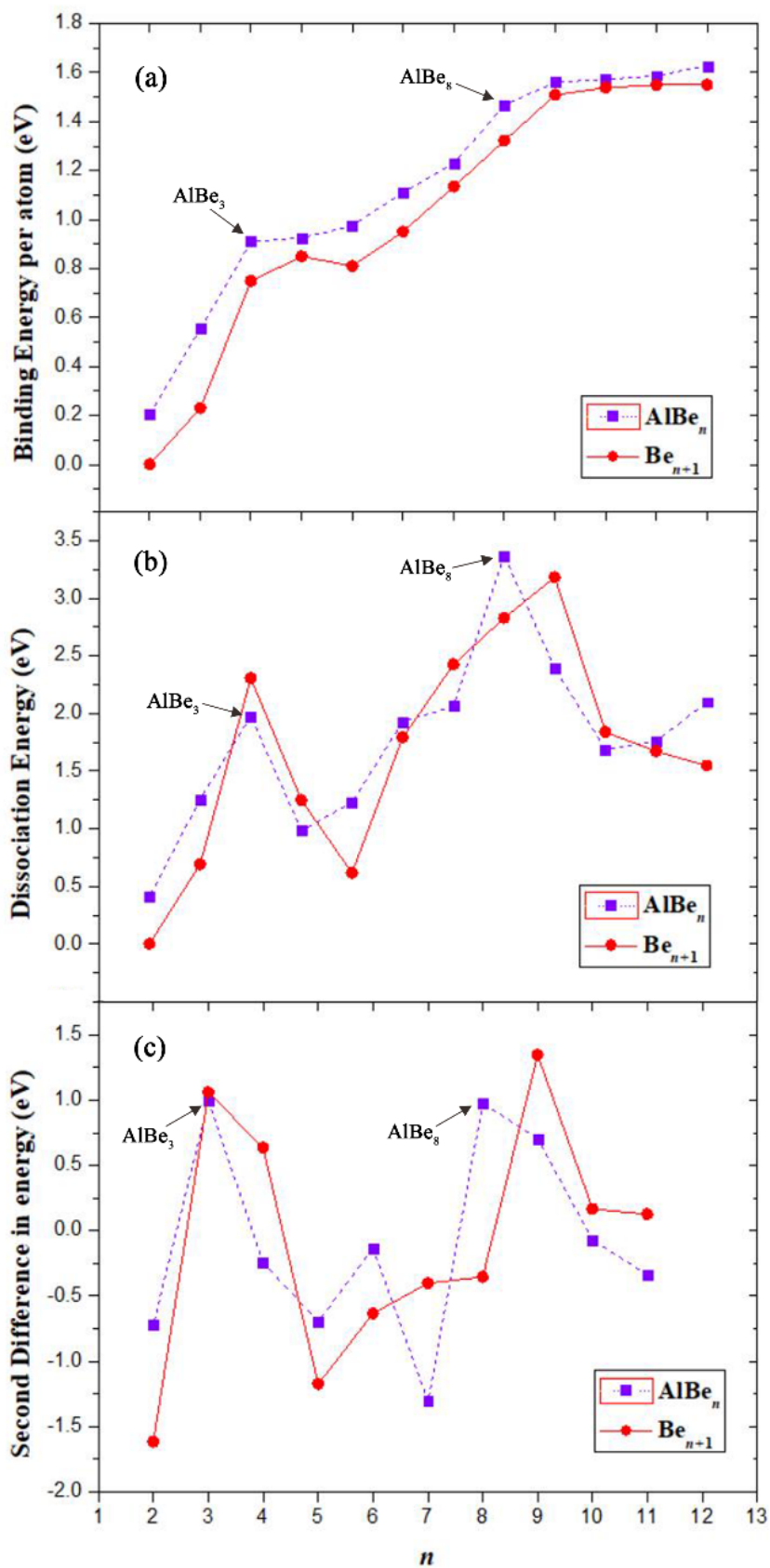


Figure 2. Size dependence of binding energies per atom (E_b), dissociation energies (ΔE), and the second difference in energy ($\Delta^2 E$) for the lowest-energy AlBe_n and Be_{n+1} ($n = 1-12$) clusters at the CCSD(T)/aug-cc-pVDZ level.

In addition, the E_b curve of AlBe_n shows two turning points at $n = 3$ and $n = 8$, indicating relatively high stability of AlBe_3 and AlBe_8 . This is more clearly reflected in varying trends of ΔE and $\Delta^2 E$. As shown in Figure 2b, the ΔE curve of AlBe_n has two distinct peaks at AlBe_3 and AlBe_8 , indicating that these two clusters are less likely to lose a Be atom. As for Be_{n+1} , two local maximum ΔE values appear at Be_4 and Be_{10} because they are magic clusters and possess unique stability according to spherical jellium model (SJM)¹⁵. A similar situation can be found in the evolution of $\Delta^2 E$ values. From Figure 2c, the curves of $\Delta^2 E$ have particular peaks at $n = 3$ and $n = 8$ for AlBe_n , and at $n = 3$ and $n = 9$ for the Be_{n+1} series. Combining all the results given above, it can be concluded that AlBe_3 and AlBe_8 have special stability among the AlBe_n clusters as do Be_4 and Be_{10} in the Be_{n+1} system.

The stability of the AlBe_n clusters is also examined in terms of adsorption energy of Al, *i.e.*, the energy released when an Al atom is attached to a pure Be_n cluster, which can be expressed as

The E_{ad} values of AlBe_n were also obtained by using the CCSD(T)//B3LYP and B3LYP methods, and the results are collected in Table S1 and plotted in Figure 3. From the figure, the two methods yield consistent results, and there are two obvious dips at AlBe_3 and AlBe_8 in both curves. These dips denote that a lot of energy is released when an Al atom is adsorbed by either Be_3 or Be_8 cluster. From Table S1, all the E_{ad} values are negative, indicating that the adsorption of Al on Be_n is a favorable process. Besides, AlBe_8 exhibits the largest E_{ad} value (-4.132 eV at CCSD(T) level and -3.872 eV at B3LYP level), so the impurity Al atom is tightly bound to the host Be_8 cluster.

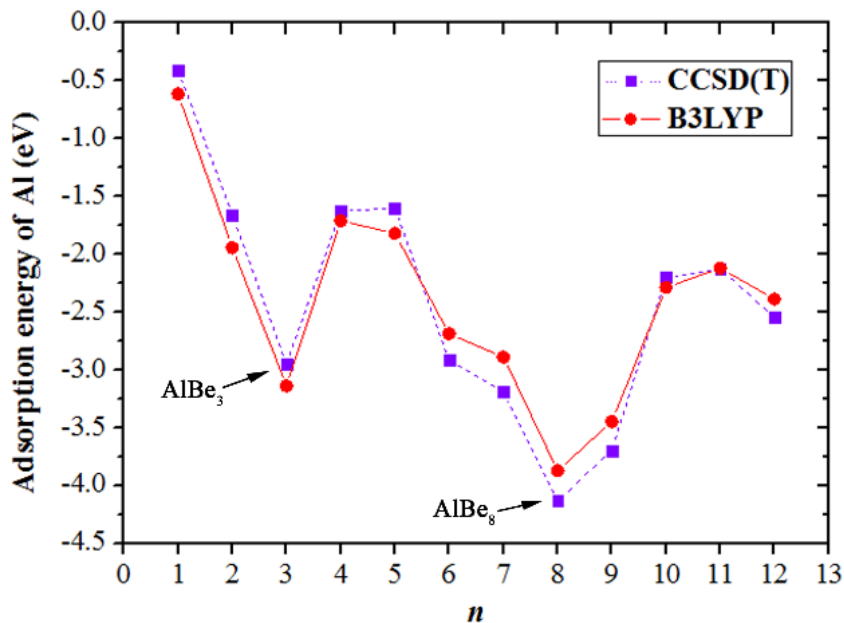


Figure 3. Size dependence of adsorption energies of Al (E_{ad}) for the lowest-energy AlBe_n ($n = 1-12$) clusters at both CCSD(T)/aug-cc-pVDZ and B3LYP/aug-cc-pVDZ levels.

3.2.2 Electronic Properties

The stability of clusters can also be evaluated by certain electronic structure related descriptors including vertical ionization potential (VIP), vertical electron affinity (VEA), chemical hardness, the highest

occupied–lowest unoccupied molecular orbital (HOMO–LUMO) energy gap, and polarizability, etc. VIP is the energy difference between the ground state of the neutral cluster and the ionized cluster that has the same geometry as the neutral. In this work, the VIP s of the lowest-energy structures of $AlBe_n$ were calculated at the B3LYP and CCSD(T) levels. From the results shown in Figure S1a, the two curves show generally consistent trends. Either curve has two striking peaks at $n = 2$ and 8, implying that the $AlBe_2$ and $AlBe_8$ clusters are not apt to lose an electron. Meanwhile, the CCSD(T) results of $AlBe_n$ and Be_{n+1} clusters are compared in Table 2. From the table, the VIP value of $AlBe_n$ is always smaller than that of its corresponding Be_{n+1} cluster except for $n = 6$.

Table 2. Vertical Ionization Potential (VIP , in eV), Vertical Electron Affinity (VEA , in eV), and Hardness (η , in eV) of the Lowest-energy Be_{n+1} and $AlBe_n$ ($n = 1-12$) Clusters at the CCSD(T)// B3LYP/aug-cc-pVDZ Level.

3.572			
n			
1			
&& 5.995 & 0.586 &			
	2.705		
	2.683		
	2.338		
	2.516		
	2.169		
	2.341		
	2.288		
	2.159		
	2.293		
	2.156		
	2.032		
	1.889		
n	Q_{Al}	NEC(Al)	NEC(Be)
1	-0.167	[core]3s ^{1.96} 3p ^{1.18} 3d ^{0.03}	[core]2s ^{1.61} 2p ^{0.22}
2	-0.621	[core]3s ^{1.90} 3p ^{1.66} 3d ^{0.05}	[core]2s ^{1.37} 2p ^{0.31}
3	-0.821	[core]3s ^{1.89} 3p ^{1.87} 4s ^{0.01} 3d ^{0.05}	[core]2s ^{1.33} 2p ^{0.37} 3s ^{0.02} 3p ^{0.01} 3d ^{0.01}
4	-0.658	[core]3s ^{1.83} 3p ^{1.77} 3d ^{0.05}	[core]2s ^{1.30-1.43} 2p ^{0.37-0.53} 3p ^{0.01} 3d ^{0.01}
5	-1.044	[core]3s ^{1.79} 3p ^{2.18} 3d ^{0.07}	[core]2s ^{1.18-1.45} 2p ^{0.37-0.56} 3s ^{0.01} 3p ^{0.01} 3d ^{0.01-0.07}
6	-1.435	[core]3s ^{1.76} 3p ^{2.56} 3d ^{0.10}	[core]2s ^{1.15-1.23} 2p ^{0.34-0.70} 3p ^{0.01} 3d ^{0.01-0.10}
7	-1.306	[core]3s ^{1.79} 3p ^{2.40} 4s ^{0.01} 3d ^{0.10}	[core]2s ^{1.20-1.25} 2p ^{0.49-0.68} 3p ^{0.01} 3d ^{0.02-0.10}
8	-1.679	[core]3s ^{1.76} 3p ^{2.78} 4s ^{0.01} 3d ^{0.12}	[core]2s ^{1.18-1.31} 2p ^{0.42-0.68} 3p ^{0.01} 3d ^{0.02-0.04}
9	-2.285	[core]3s ^{1.78} 3p ^{3.30} 4s ^{0.05} 3d ^{0.15}	[core]2s ^{1.13-1.27} 2p ^{0.43-0.59} 3p ^{0.01-0.03} 3d ^{0.01-0.05}
10	-2.403	[core]3s ^{1.73} 3p ^{3.48} 4s ^{0.04} 3d ^{0.15}	[core]2s ^{1.07-1.28} 2p ^{0.50-0.64} 3p ^{0.01-0.03} 3d ^{0.02-0.05}
11	-2.336	[core]3s ^{1.71} 3p ^{3.41} 4s ^{0.03} 3d ^{0.17}	[core]2s ^{1.10-1.34} 2p ^{0.34-0.71} 3p ^{0.01-0.03} 3d ^{0.02-0.06}
12	-2.331	[core]3s ^{1.69} 3p ^{3.42} 4s ^{0.03} 3d ^{0.18}	[core]2s ^{1.07-1.37} 2p ^{0.31-0.76} 3p ^{0.01-0.03} 3d ^{0.02-0.05}

can be found from Figure S2 that, the Al charge increases as the size of cluster grows and tends to flatten

out from AlBe_9 onwards. Note that this varying trend roughly corresponds to that of coordination number of Al in the AlBe_n clusters, suggesting that higher coordination number of impurity atom is beneficial to intracuster charge transfer in this case. According to Table 3, the 3s states of Al lose 0.04–0.31 electrons, while the 3p states get 0.18–2.48 electrons. As for the Be atoms, their 2s orbitals lose 0.39–0.93 electrons, while the 2p states get 0.22–0.76 electrons. Hence, the charge transfer within the AlBe_n clusters is mainly from the 3s orbital of Al and 2s orbitals of Be atoms to the 3p orbital of Al and 2p orbitals of Be atoms. By contrast, the contributions from other orbitals of Al and Be are negligible.

The HOMO-LUMO gaps of the AlBe_n clusters at the B3LYP level are listed in Table 1 and plotted in Figure S3. From the figure, there are three obvious peaks at AlBe_3 , AlBe_5 and AlBe_8 , indicating relatively high stability of these three clusters. In particular, the AlBe_8 cluster possesses the largest HOMO-LUMO gap of 2.817 eV, which not only is larger than the experimental gap value of 1.9 eV for the kinetically stable C_{60} ,^[47] but also exceeds that of 2.53 eV (computed at the same level) for the chemically inert superatom Al_{13}^- .^[48] For comparison, the HOMO-LUMO gaps of the Be_{n+1} clusters are also depicted in Figure S3. It can be found that substituting an Al atom for a Be atom enlarges the HOMO-LUMO gaps of Be_8 and Be_{10} clusters by 0.689 eV and 0.398 eV, respectively, while the Al substitution effect is insignificant for Be_{11} and Be_{13} clusters and is negative for the other beryllium clusters.

Finally, the evolution of polarizability per atom of AlBe_n ($n = 1$ –12) is considered since the static polarizability is an important measure of electronic properties of clusters. From the results shown in Figure 4, a turning point at $n = 3$ can be found, which squares with the geometry transformation from planar to stereoscopic at AlBe_3 . For comparison, the polarizability per atom of the lowest-energy Be_{n+1} clusters are also given in Figure 4. From the figure, both curves show generally decreasing trends with increasing cluster size, and gradually become stable for larger sizes. Besides, substituting a Be atom in Be_{n+1} with an Al atom always brings about a larger polarizability to the doped cluster, although the Al-substitution effect is less prominent for larger-sized ones. Hence, the AlBe_n clusters are more polarizable compared with their corresponding Be_{n+1} clusters. Note that there is a relatively large polarizability gap between Be_6 and AlBe_5 , which can be attributed to the large structural discrepancy between these two clusters since polarizability is sensitive to the shape of the system.^[50]

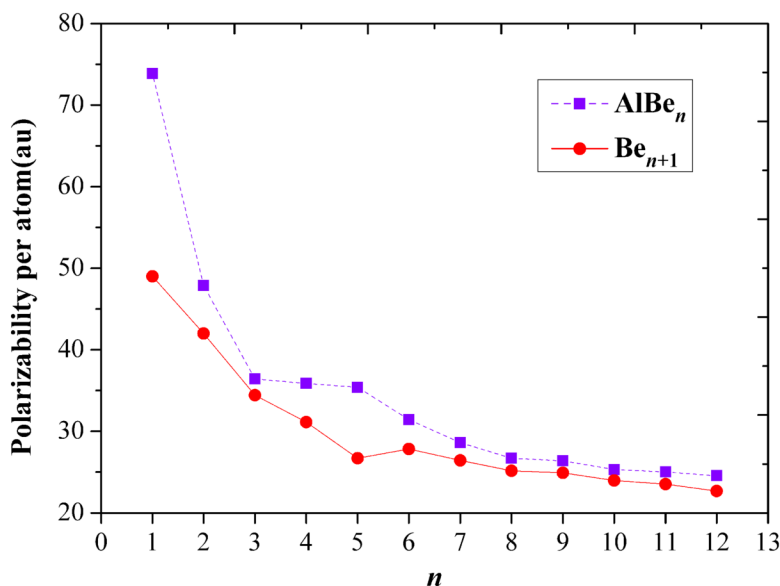


Figure 4. Size dependence of polarizabilities per atom for the lowest-energy AlBe_n and Be_{n+1} ($n = 1$ –12)

clusters at the B3LYP/aug-cc-pVDZ level.

3.3 In-depth study of AlBe_3 and AlBe_8

Based on the preceding analysis of energetic and electronic properties, it is interesting to find that the AlBe_3 and AlBe_8 clusters possess special stability among the AlBe_n series. Hence, the electronic structure and density of states (DOS) of these two clusters are further investigated. To facilitate comparison, the total and partial density of states (TDOS and PDOS) of AlBe_3 and AlBe_8 as well as their corresponding Be_4 and Be_9 clusters are plotted as a function of energy in Figure 5, in which their valence molecular orbitals (MOs) obtained at the RMP2//B3LYP level are also illustrated.

From Figure 5b, the singly-occupied HOMO orbital of AlBe_3 exhibits dominant s state, the HOMO-1 to HOMO-3 orbitals present typical p shape, and the HOMO-4 orbital shows spherically symmetric s character. So the valence electron configuration of AlBe_3 is $1S^2 1P^6 2S^1$. As for the AlBe_8 cluster, its nineteen valence electrons are arranged in the $1S^2 1P^6 1D^{10} 2S^1$ pattern, which accords well with the prediction of the spherical jellium model.^[15] Compared with AlBe_8 , the triplet Be_9 cluster is one D electron less and has a electronic shell structure of $1S^2 1P^6 1D^9 2S^1$ (see Figure 5c). As the studied AlBe_n clusters are all open-shell species, there are not any shell-closed magic clusters in this series. However, the AlBe_3 and AlBe_8 clusters do exhibit enhanced stability relative to their congeners. A possible explanation is that both of them are one electron short of shell closure, and their desire for an additional electron makes the component atoms bind so tightly with each other that the clusters are stable against dissociation of any kind.

From Figure 5, the introduction of Al impurity has more effect on the DOS of p-type molecular orbitals of beryllium clusters. The comparison between TDOS of Be_4 and AlBe_3 shows that the peak near -6 eV for the former splits into two peaks in the latter. Similarly, the peak around -9.5 eV in the TDOS plot of Be_9 also splits into two peaks at -9.5 eV and -10 eV in that of AlBe_8 . In contrast, the Al doping effect is minor on the DOS of other states.

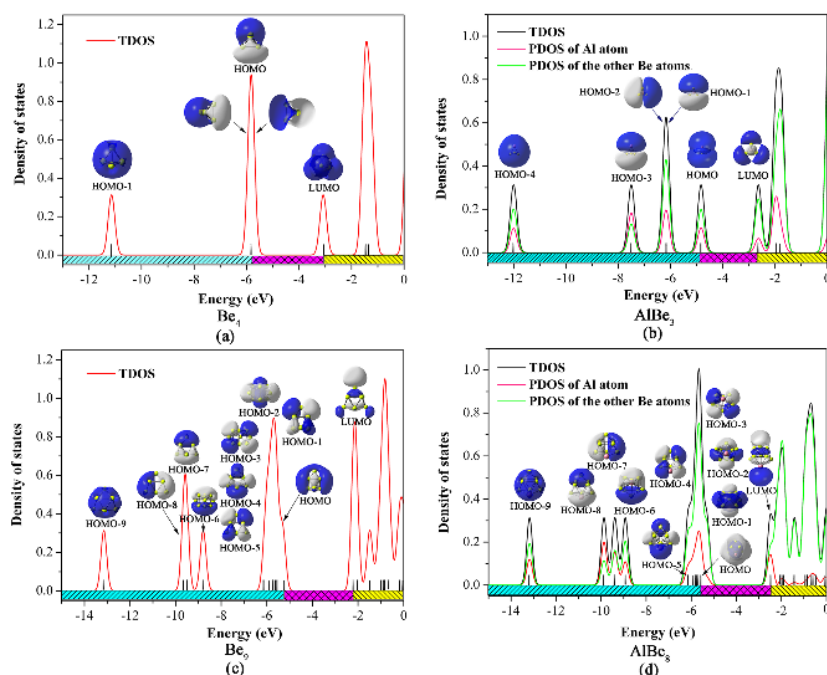


Figure 5. Density of states (DOS) and valence molecular orbitals (shown as insets) of the AlBe_3 , AlBe_8 , Be_4 , and Be_9 clusters.

Conclusions

The structures, relative stability, and electronic properties of the lowest-energy AlBe_n ($n = 1-12$) clusters were systematically studied by high-level *ab initio* and density functional theories. The geometry transformation from planar to stereoscopic occurs at AlBe_3 in this series. The impurity Al atom prefers to reside outside the host Be_n cluster until $n = 12$ and only slightly affects the configuration of the latter. NBO analysis reveals that $0.167 \sim 2.403|e|$ charge flows from the host Be_n to the Al atom, which might be due to the larger electronegativity of Al than Be. The evolutions of E_b , $\Delta^2 E$, ΔE , E_{ad} , and HOMO-LUMO gap with cluster size show special stability of AlBe_3 and AlBe_8 among the AlBe_n clusters. Moreover, a comparison has been made between AlBe_n and pure beryllium clusters, and it is found that substituting an Al atom for a Be atom in Be_{n+1} results in enhanced binding energy and polarizability but decreased chemical hardness of the system.

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Keywords: doped cluster, Be-Al alloy, bimetallic, optimization, stability

References and Notes

1. X. Li, A. E. Kuznetsov, H.-F. Zhang, A. I. Boldyrev, L.-S. Wang, *Science*, **2001**, 291, 859-861.
2. O. Thomas, W. Zheng, S. Xu, K. Bowen, *Phys. Rev. Lett.* **2002**, 89, 213403.
3. D. E. Bergeron, A. W. Castleman, T. Morisato, S. N. Khanna, *Science*, **2004**, 304, 84-87.
4. D. E. Bergeron, P. J. Roach, A. W. Castleman, N. O. Jones, S. N. Khanna, *Science*, **2005**, 307, 231-235.
5. A. I. Boldyrev, L.-S. Wang, *Chem. Rev.* **2005**, 105, 3716-3757.
6. L. Cheng, K. Xiao-Yu, L. Zhi-Wen, M. Ai-Jie, M. Yan-Ming, *J. Phys. Chem. A*, **2011**, 115, 9273-9281.
7. Z. Luo, C. J. Grover, A. C. Reber, S. N. Khanna, A. W. Castleman, Jr., *J. Am. Chem. Soc.* **2013**, 135, 4307-4313.
8. R. Burgert, H. Schnockel, A. Grubisic, X. Li, S. T. Stokes, K. H. Bowen, G. F. Gantefor, B. Kiran, P. Jena, *Science*, **2008**, 319, 438-442.
9. P. J. Roach, W. H. Woodward, A. W. C. Jr., A. C. Reber, S. N. Khanna, *Science*, **2009**, 323.
10. S. A. Claridge, J. A. W. Castleman, Shiv N. Khanna, C. B. Murray, A. Sen, P. S. Weiss, *ACS Nano*, **2009**, 3, 244-255.
11. J. A. W. Castleman, S. N. Khanna, *J. Phys. Chem. C*, **2009**, 113, 2664-2675.
12. M. Qian, A. C. Reber, A. Ugrinov, N. K. Chaki, S. Mandal, Hector M. Saavedra, S. N. Khanna, A. Sen, P. S. Weiss, *ACS Nano*, **2010**, 4, 235-240.
13. N. K. Chaki, S. Mandal, A. C. Reber, M. Qian, H. M. Saavedra, P. S. Weiss, S. N. Khanna, A. Sen, *ACS Nano*, **2010**, 4, 5813-5818.
14. S. Mandal, A. C. Reber, M. Qian, P. S. Weiss, S. N. Khanna, A. Sen, *Acc. Chem. Res.* **2013**.
15. (a) W. D. Knight, K. Clemenger, W. A. d. Heer, A. Saunders, *Phys. Rev. Lett.* 1984, 52, 2141-2143.
(b) W. Ekardt, *Phys. Rev. B*, **1984**, 29, 1558-1564.
16. Baltenkov A S, Manson S T, Msezane A Z, *J. Phys. B: At. Mol. Opt. Phys.* **2015**, 48(18): 185103.
17. Varas A, García-González P, Feist J, et al. Quantum plasmonics: from jellium models to ab initio calculations[J]. *Nanophotonics*, **2016**.
18. V. E. Bondybey, *Chem. Phys. Lett.* **1984**, 109, 436-441.
19. J. Störck, W. Meyer, *Chem. Phys. Lett.* **1996**, 258, 421-426.
20. J. M. L. Martin, *Chem. Phys. Lett.* 1999, 303, 399-407.
21. K. Patkowski, V. Spirko, K. Szalewicz, *Science*, **2009**, 326, 1382-1384.
22. J. M. Merritt, V. E. Bondybey, M. C. Heaven, *Science*, 2009, 324, 1548-1551.

23. D. R. Lide, ed., CRC Handbook of Chemistry and Physics, CRC Press, Boca Raton, **2008** . 89th.
24. M. C. Heaven, J. M. Merritt, V. E. Bondybey, *Annu. Rev. Phys. Chem.* **2011** , 62, 375-393.
25. J. Wang, G. Wang, J. Zhao, *J. Phys.: Condens. Mat.***2001** , 13, 753–758.
26. V. Cerowski, B. K. Rao, S. N. Khanna, P. Jena, S. Ishii, K. Ohno, Y. Kawazoe, *J. Chem. Phys.* **2005** , 123, 074329.
27. Parsonage T. *Mater. Sci. tech.* **2000** , 16(7-8): 732-738.
28. Schuster G, Pokross C, *Light Metals.* **2013** , 2013: 259-264.
29. Sweeney M, Acreman M, Vettese T, Application and testing of additive manufacturing for mirrors and precision structures[C].**2015** : 957406-957406-13.
30. Previtali B. Metal Matrix Composites: Casting Processes[J]. Wiley Encyclopedia of Composites, **2012** .
31. J. Tong, Y. Li, D. Wu, Z.-R. Li, X.-R. Huang, *J. Chem. Phys.***2009** , 131, 164307.
32. M. Saunders, *J. Comput. Chem.* **2004** , 25, 621-626.
33. E. D. Glendenning, A. E. Reed, J. E. Carpenter, F. Weinhold, NBO Version 3.1, Theoretical Chemistry Institute, University of Wisconsin, Madison, 1996.
34. M. J. Frisch, H. B. Schlegel, G. E. Scuseria, , J. R. C. M. A. Robb, G. Scalmani, V. Barone, B. Mennucci, , H. N. G. A. Petersson, M. Caricato, X. Li, H. P. Hratchian, , J. B. A. F. Izmaylov, G. Zheng, J. L. Sonnenberg, M. Hada, , K. T. M. Ehara, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, , O. K. Y. Honda, H. Nakai, T. Vreven, J. A. Montgomery, Jr., , F. O. J. E. Peralta, M. Bearpark, J. J. Heyd, E. Brothers, , V. N. S. K. N. Kudin, R. Kobayashi, J. Normand, , A. R. K. Raghavachari, J. C. Burant, S. S. Iyengar, J. Tomasi, , N. R. M. Cossi, J. M. Millam, M. Klene, J. E. Knox, J. B. Cross, , C. A. V. Bakken, J. Jaramillo, R. Gomperts, R. E. Stratmann, , A. J. A. O. Yazyev, R. Cammi, C. Pomelli, J. W. Ochterski, , K. M. R. L. Martin, V. G. Zakrzewski, G. A. Voth, , J. J. D. P. Salvador, S. Dapprich, A. D. Daniels, , J. B. F. O. Farkas, J. V. Ortiz, J. Cioslowski, and D. J. Fox, Gaussian 09, Revision A.01, Gaussian, Inc., Wallingford CT,**2009** .
35. R. Dennington, T. Keith, J. Millam, GaussView, Version 5, Semichem, Inc., Shawnee Mission, KS, **2009** .
36. S. Srinivas and J. Jellinek, *J. Chem. Phys.* , **2004** , 121, 7243.
37. J. M. Merritt, V. E. Bondybey, M. C. Heaven, *Phys. Chem. Chem. Phys.* **2008** , 10, 5403.
38. VW Ribas, LT Ueno, O Roberto-Neto, *Chem. Phys.* **2006** , 330(1): 295-300.
39. J Wang, D Zhai, F Guo, *Theor. Chem. Acc.* **2008** , 121(3-4): 165-172.
40. X.-J. Feng, Y.-H. Luo, *J. Phys. Chem. A.* **2007** , 111, 2420-2425.
41. H.-P. Cheng, R. Barnett, U. Landman, *Phys. Rev. B* .**1993** , 48, 1820-1824.
42. A. Dhavale, V. Shah, D. G. Kanhere, *Phys. Rev. A* .**1998** , 57, 4522-4527.
43. R. Zope, S. Blundell, C. Guet, T. Baruah, D. Kanhere, *Phys. Rev. A* . **2001** , 63.043202.
44. J. Xiang, S. H. Wei, X. H. Yan, J. Q. You, Y. L. Mao, *J.Chem. Phys.* **2004** , 120, 4251.
45. M. Wang, G. Qiu, X. Huang, Z. Du, Y. Li, *J. Phy.: Condens. Mat.***2009** , 21, 046004.
46. D.-L. Chen, W. Tian, C.-C. Sun, *Phys. Rev. A* . **2007** , 75. 013201.
47. G.-f. Zhao, J. Zhang, Q. Jing, Y.-h. Luo, Y.-x. Wang, *J. Chem. Phys.* **2007** , 127, 234312.
48. J. C. Slater, *J. Chem. Phys.* **1964** , 41, 3199.
49. R. G. Parr, R. G. Pearson, *J. Am. Chem. Soc.* **1983** , 105, 7512–7516.
50. W. D. Knight, K. Clemenger, W. A. de Heer, W. A. Saunders, *Phys. Rev. B* . 31, 2539 (**1985**).